

In the claims:

Please amend the claims as follows.

1. (Cancelled)
2. (Currently Amended) A voltage reference generator circuit according to claim 17, wherein the first circuitry comprises a bipolar transistor, the base emitter voltage of which is susceptible to variations with process technology.
3. (Original) A voltage reference generator circuit according to claim 2, wherein the bipolar transistor has a collector connected to an upper supply rail, a base connected to an input node and an emitter connected to a resistive chain.
4. (Original) A voltage reference generator circuit according to claim 3, wherein the resistive chain comprises a current setting resistor and wherein the first circuitry comprises a voltage generator circuit adapted to generate a voltage which is proportional to absolute temperature across said current setting resistor.
- 5-6. (Cancelled)
7. (Currently Amended) A voltage reference generator circuit for generating a reference voltage of a predetermined value comprising:  
first circuitry adapted to generate a first voltage which is substantially independent of temperature and related to a component parameter susceptible to variations with process technology;  
second circuitry adapted to generate an offset voltage of a value such that the sum of the first voltage and the offset voltage is said predetermined value, and wherein the second circuitry comprises components whose parameters are variably selectable without affecting the first voltage, and wherein the second circuitry comprises current generating circuitry that  
~~A voltage reference generator circuit according to claim 6, wherein the current generating circuitry comprises a current source and a bipolar transistor connected in series between upper and lower supply rails.~~

8. (Currently Amended) A voltage reference generator circuit according to claim 67, wherein the current generated by the current generating circuit is supplied through first and second compensation resistors.

9. (Original) A voltage reference generator circuit comprising:  
a first bipolar transistor connected in series with a resistive chain between upper and lower supply rails and having an input node at its base;  
a current generating circuit connected to supply a current to a node of said resistive chain, said resistive chain including a compensation resistor connected between said node and said lower supply rail;  
voltage generating means for generating a voltage proportional to absolute temperature across a current setting resistor of said resistive chain;  
wherein the resistive value of the compensation resistor is selectable independently of the values of other components in the resistive chain, whereby an offset voltage across said compensation resistor is independently settable.

10. (Cancelled)

11. (Currently Amended) A voltage generator, comprising:  
an offset circuit operable to develop an offset voltage and operable to adjust the offset value as a function of temperature; and  
a voltage generation circuit coupled to the offset circuit, the voltage generation circuit operable to develop a first reference voltage and adjust the value of the first reference voltage as a function of temperature, and operable to provide an output reference voltage equal to the first reference voltage plus the offset voltage; and  
~~The voltage generator of claim 10 wherein~~  
the voltage generation circuit includes a bipolar transistor having a base-emitter voltage that is a function of temperature; and  
the offset circuit includes a bipolar transistor having a base-emitter voltage that is a function of temperature.

12. (Original) The voltage generator of claim 11 wherein

the voltage generation circuit includes a resistor network coupled between an emitter of the bipolar transistor and a node; and

the offset circuit comprises a resistive element having a first terminal coupled to the node and a second terminal adapted to receive a reference voltage.

13. (Original) The voltage generator of claim 12 wherein the resistor network comprises:

a first, second, and third resistor coupled in series between the emitter and the node, and a temperature voltage developing element being coupled in parallel with the second resistor.

14. (Original) The voltage generator of claim 12 wherein the offset circuit further comprises:

a current source having a first terminal adapted to receive a supply voltage and a second terminal; and

a resistive element having a first terminal coupled to a base of the bipolar transistor and a second terminal coupled to the node; and

wherein a collector and the base of the bipolar transistor are coupled to the second terminal of the current source and an emitter of the bipolar transistor is adapted to receive a reference voltage.

15. (Currently Amended) An integrated circuit, comprising:  
a voltage generator, comprising,

an offset circuit operable to develop an offset voltage and operable to adjust the offset value as a function of temperature, wherein the offset circuit includes a bipolar transistor having a base-emitter voltage that is a function of temperature, and

a voltage generation circuit coupled to the offset circuit, the voltage generation circuit operable to develop a first reference voltage and adjust the value of the first reference voltage as a function of temperature, and operable to provide an output reference voltage equal to the first reference voltage plus the offset voltage, wherein the voltage generation circuit includes a bipolar transistor having a base-emitter voltage that is a function of temperature.

16. (Original) The integrated circuit of claim 15 wherein the integrated circuit comprises a memory device.

17-29. (Cancelled)